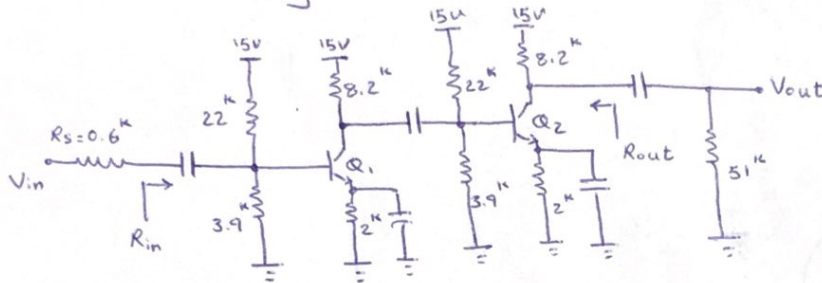


In the name of God

Assignment 4:

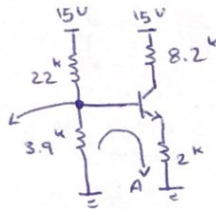
1. calculate the voltage gain, input resistance and output resistance of the following circuit.



$$\beta = 100$$

DC analysis:

$$V_A = \frac{3.9 \times 15}{3.9 + 22} = 2.25 \text{ V}$$

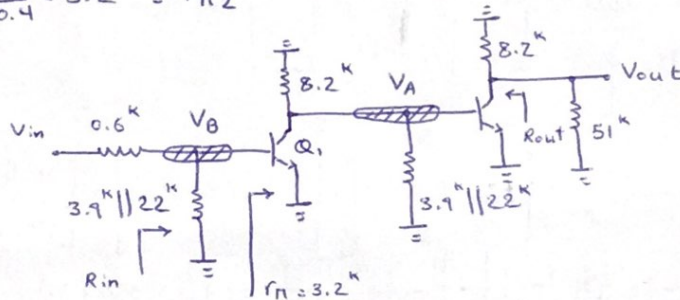


$$\text{KVL @ A: } -2.25 + (22 \parallel 3.9) \frac{I_C}{100} + 0.7 + 2 I_C = 0$$

$$I_C \left(\frac{3.9}{100} + 2 \right) = 2.25 - 0.7 \Rightarrow I_{C1} = 0.76 \text{ mA} = I_{C2}$$

$$\begin{cases} g_{m1} = 40 I_{C1} = 30.4 \text{ mmho} = g_{m2} \\ r_{\pi 1} = \frac{\beta}{g_{m1}} = \frac{100}{30.4} = 3.2 \text{ k} = r_{\pi 2} \\ r_{o1} = \infty = r_{o2} \end{cases}$$

ac Analysis:



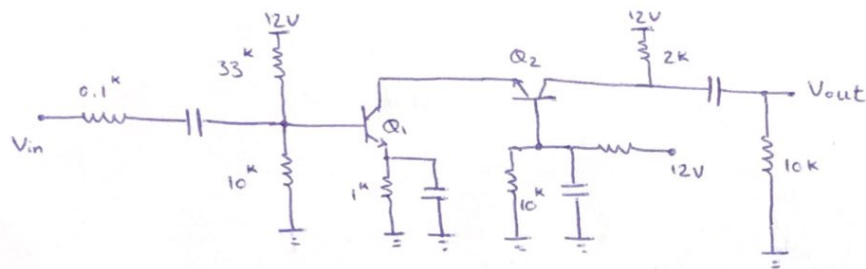
$$A_v = \frac{V_{out}}{V_{in}} = \frac{V_{out}}{V_A} \times \frac{V_A}{V_B} \times \frac{V_B}{V_{in}} = \left[g_{m2} (R_{C2} \parallel R_{O2}) \right] \cdot \left[-g_{m1} (R_{C1} \parallel r_{o1}) \right] \cdot \left[\frac{3.9 \parallel 22 \parallel r_{\pi 1}}{0.6 + 3.9 \parallel 22 \parallel r_{\pi 1}} \right]$$

$$= \left[-30.4 (8.2 \parallel 51 \parallel \infty) \right] \times \left[-30.4 (8.2 \parallel 3.9 \parallel 22 \parallel 3.2 \parallel \infty) \right] \times \left[\frac{3.9 \parallel 22 \parallel 3.2}{0.6 + 3.9 \parallel 22 \parallel 3.2} \right]$$

$$\approx 11007$$

$$R_{in} = 3.9 \parallel 22 \parallel r_{\pi} \approx 1.62 \text{ k}, \quad R_{out} = 8.2 \parallel \overbrace{r_o}^{\infty} = 8.2 \text{ k}$$

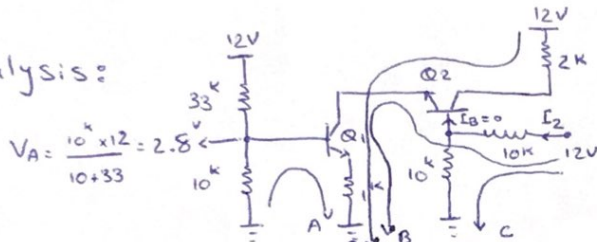
2. In the circuit shown below, determine the voltage gain.



$$\begin{cases} Q_1: \beta_1 = 100 \\ Q_2: \alpha_2 = 1 \rightarrow \beta_2 = \infty \end{cases}$$

$$\text{hint: } \begin{cases} \alpha = \frac{\beta}{\beta+1} \\ \beta = \frac{\alpha}{1-\alpha} \end{cases}$$

dc analysis:



$$V_A = \frac{10^4 \times 12}{10 + 33} = 2.8 \text{ V}$$

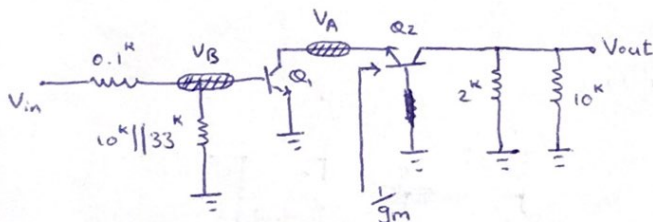
$$\text{KVL @ A: } -2.8 + (10^4 \parallel 33^4) \cdot \frac{I_{C1}}{100} + 0.7 + 1^4 I_{C1} = 0 \Rightarrow I_{C1} = 1.96 \text{ mA} \rightarrow \begin{cases} g_m = 78.4 \text{ mho} \\ r_{\pi} = 1.27^4 \\ r_o = \infty \end{cases}$$

$$\text{KVL @ B: } -12 + 10^4 (I_2) + 0.7 + V_{CE1} + 1^4 I_{C1} = 0 \xrightarrow{I_{C1} = 1.96 \text{ mA}} V_{CE1} = 3.34 \text{ V} > V_{CE, \text{sat}}$$

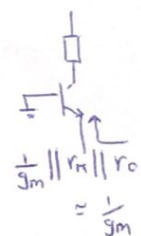
$$\text{KVL @ C: } -12 + 10^4 I_2 + 10^4 I_2 = 0 \Rightarrow I_2 = 0.6 \text{ mA}$$

$$\text{KVL @ D: } -12 + 2^4 I_C + V_{CE2} + V_{CE1} + 1^4 I_C = 0 \xrightarrow{I_C = 1.96 \text{ mA}, V_{CE1} = 3.34} V_{CE2} = 2.78 > V_{CE, \text{sat}}$$

ac analysis:

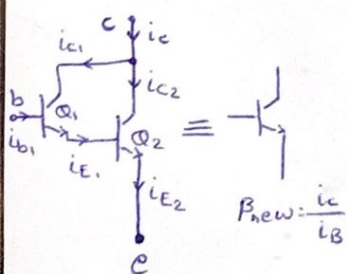


hint:



$$\begin{aligned} A_v &= \frac{V_{out}}{V_{in}} = \frac{V_{out}}{V_A} \times \frac{V_A}{V_B} \times \frac{V_B}{V_{in}} = \left[+g_m (R_C \parallel R_o) \right] \times \left[-g_m (R_C \parallel R_o) \right] \times \left[\frac{10^4 \parallel 33^4}{(10^4 \parallel 33^4) + 0.1^4} \right] \\ &= \left[78.4 (2^4 \parallel 10^4 \parallel \infty) \right] \times \left[-78.4 \left(\frac{1}{78.4} \right) \right] \times \left[\frac{10^4 \parallel 33^4}{(10^4 \parallel 33^4) + 0.1^4} \right] = 130 \times (-1) \times 0.9 = -117 \end{aligned}$$

3. The following structure is known to be the "Darlington pair" Configuration and is used in order to increase the β of single transistor. This configuration can be modeled as a single NPN transistor. Determine its equivalent r_{π} , g_m and β .



$$\times i_{C1} = \beta_1 i_{B1} \Rightarrow \beta_{\text{new}} = \frac{i_C}{i_{B1}} = \beta_1 + \beta_2 (\beta_1 + 1)$$

$$\times i_{E1} = (\beta_1 + 1) i_{B1}$$

$$= \beta_1 + \beta_2 + \beta_1 \beta_2$$

$$\times i_{C2} = \beta_2 i_{E1} = \beta_2 i_{B1}$$

$$g_{m, \text{new}} = 40 I_C$$

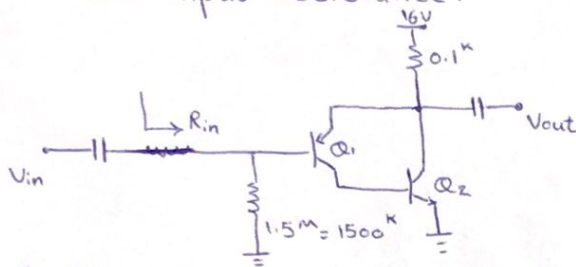
$$\times i_{B2} = i_{E1}$$

$$r_{\pi, \text{new}} = \frac{\beta_{\text{new}}}{g_{m, \text{new}}} = \frac{\beta_1 + \beta_2 + \beta_1 \beta_2}{40 I_C}$$

$$\times i_{C2} = \beta_2 (\beta_1 + 1) i_{B1}$$

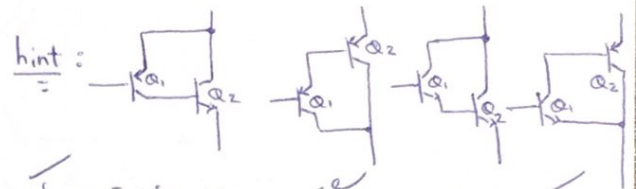
$$\times i_C = i_{C1} + i_{C2} = \beta_1 i_{B1} + \beta_2 (\beta_1 + 1) i_{B1} = i_{B1} (\beta_1 + \beta_2 (\beta_1 + 1))$$

4. The following Configuration is called the "Sziklai Pair" or the Complementary Darlington pair. This Configuration can be used to construct a PNP transistor with a large β . For the following circuit, determine the Voltage gain and input resistance.



$$\beta_1 = 160$$

$$\beta_2 = 200$$

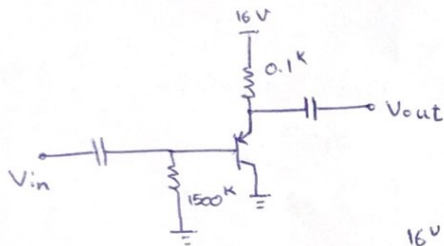


نمای ترکیب های پال زوج دارلینگتون هستند. اثبات می شود
 $\beta_{new} \approx \beta_1 \beta_2$ در ترکیب های پال به صورت زیر است:

$$\beta_{new} \approx \beta_1 \beta_2 = 160 \times 200 = 32000$$

$$g_m = 40 I_c$$

$$r_{\pi} = \frac{\beta_{new}}{g_m}$$



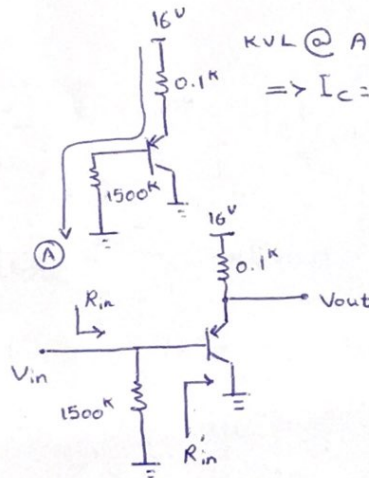
dc analysis:

$$KVL @ A: -16V + 0.1k I_c + 0.7 + 1500k \frac{I_c}{32000} = 0$$

$$\Rightarrow I_c = 109 \mu A \rightarrow g_m = 40(109) = 4360 \text{ mmho}$$

$$r_{\pi} = \frac{32000}{4360} = 7.3k$$

ac analysis:

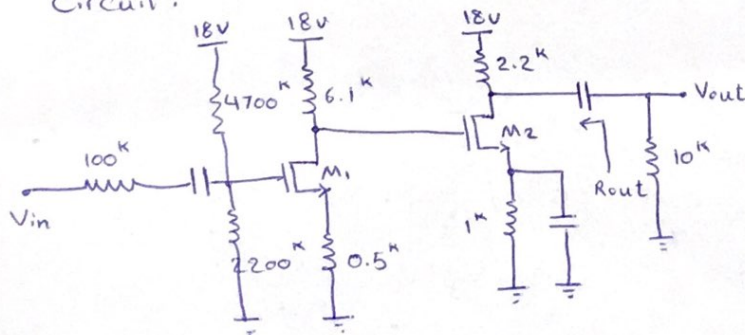


$$A_v = \frac{V_{out}}{V_{in}} = \frac{R_E}{R_E + \frac{1}{g_m}} = \frac{0.1k}{0.1k + \frac{1}{4360}} \approx 1$$

$$R_{in} = R'_{in} \parallel 1500k = 3207.3k \parallel 1500k \approx 1022k$$

$$R'_{in} = r_{\pi} + (\beta + 1)R_E = 7.3k + (32000)(0.1k) = 3207.3k\Omega$$

5. Determine the Voltage gain and the output resistance of the following Circuit.

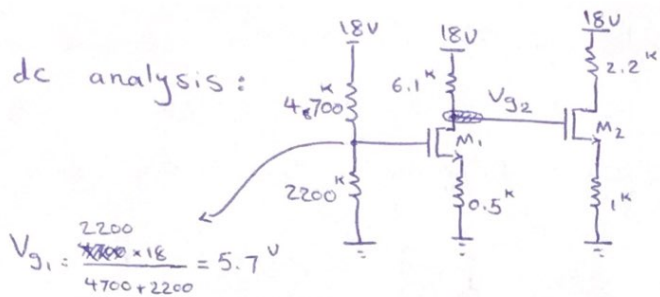


$$\beta_1 = 0.5 \frac{mA}{V^2}, \quad \beta_2 = 0.3 \frac{mA}{V^2}$$

$$V_{th1} = 2V, \quad V_{th2} = 2.6V$$

$$r_{ds1} = 75k, \quad r_{ds2} = 100k$$

dc analysis:



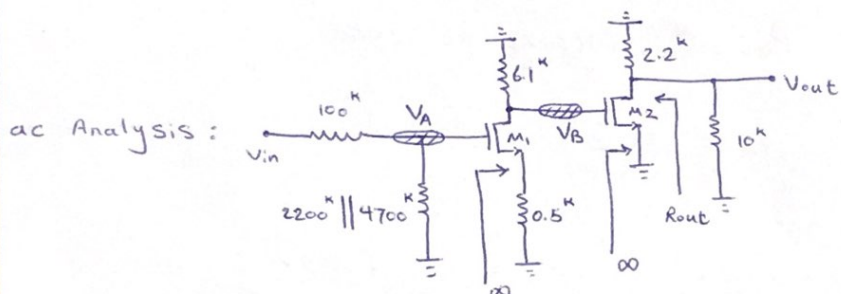
$$V_{G1} = \frac{2200 \times 18}{4700 + 2200} = 5.7 \text{ V}$$

$$I_{D1} = \frac{\beta_1}{2} (V_{GS1} - V_{th1})^2 = \frac{0.5}{2} (5.7 - 0.5 I_{D1} - 2)^2$$

$$\begin{cases} I_{D1} = 28.9 \text{ mA} \\ I_{D1} = 1.8 \text{ mA} \checkmark \end{cases} \rightarrow g_{m1} = \sqrt{2\beta_1 I_{D1}} = 1.3 \text{ mmho}$$

$$18 - V_{G2} = 6.1 \text{ k} I_{D1} \xrightarrow{I_{D1} = 1.8 \text{ mA}} \boxed{V_{G2} = 7.02 \text{ V}}$$

$$I_{D2} = \frac{\beta_2}{2} (V_{GS2} - V_{th2})^2 = \frac{0.3}{2} (7.02 - I_{D2} - 2.6 \text{ V})^2 = \begin{cases} I_{D2} = 14.12 \text{ mA} \\ I_{D2} = 1.38 \text{ mA} \checkmark \end{cases} \rightarrow g_{m2} = 0.9 \text{ mmho}$$

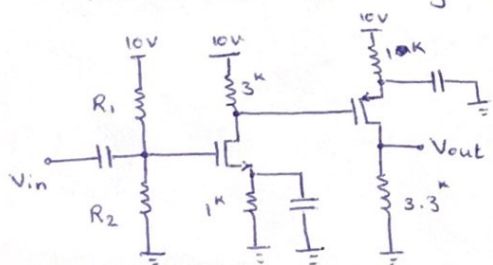


$$R_{out} = 2.2 \text{ k} \parallel r_{ds2} = 2.2 \text{ k} \parallel 100 \text{ k} \approx 2.2 \text{ k}$$

$$A_v = \frac{V_{out}}{V_{in}} = \frac{V_{out}}{V_B} \times \frac{V_B}{V_A} \times \frac{V_A}{V_{in}} = [-g_{m2} (R_{D2} \parallel r_{ds2})] \times \left[\frac{-R_{D1}}{\frac{1}{g_{m1}} + R_{S1}} \right] \times \left[\frac{2200 \parallel 4700}{(2200 \parallel 4700) + 100} \right]$$

$$= \left[-0.9 (2.2 \text{ k} \parallel 10 \text{ k} \parallel 100 \text{ k}) \right] \times \left[\frac{6.1 \text{ k}}{\frac{1}{1.3} + 0.5 \text{ k}} \right] \times \left[\frac{2200 \parallel 4700}{(2200 \parallel 4700) + 100} \right] \approx \boxed{-7.18}$$

5. a) Specify R_1 and R_2 so that the bias current of M_1 will be equal to 1 mA .
b) Calculate the voltage gain and the output resistance.

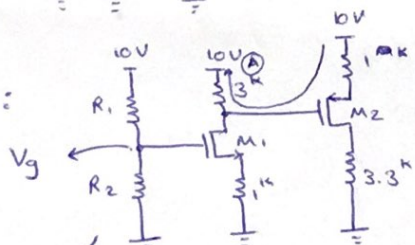


$$\beta = 0.25 \frac{\text{mA}}{\text{V}^2}$$

$$|V_{th}| = 0.5 \text{ V}$$

$$\lambda = 0 \rightarrow r_{ds} = \infty$$

dc analysis:



$$V_G = \frac{R_2 \times 10}{R_1 + R_2}$$

$$V_{GS1} = \sqrt{\frac{I_{D1}}{\frac{\beta_1}{2}}} + V_{th1} = \sqrt{\frac{1}{\frac{0.25}{2}}} + 0.5 = \boxed{3.3}$$

$$V_{GS1} = V_G - V_S = \frac{10R_2}{R_1 + R_2} - 1 \text{ (V)} = 3.3 \text{ V}$$

$$\frac{10R_2}{R_1 + R_2} = 4.3 \text{ V} \xrightarrow{R_2 = 1000 \text{ k}} \frac{10(1000)}{R_1 + 1000} = 4.3 \Rightarrow \boxed{R_1 = 1325.5 \text{ k}}$$

b) KVL @ A: $-10 + 10^3 I_{D2} + V_{sg2} - 3^k (1^m) + 10 = 0 \Rightarrow V_{sg2} = 3 - 1^k I_{D2}$

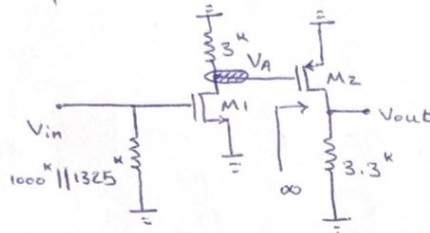
$I_{D2} = \frac{\beta}{2} (V_{sg} - V_{th})^2 = \frac{0.25}{2} (3 - 1^k I_{D2} - 0.5)^2 = \begin{cases} I_{D2} = 0.5 \text{ mA} \checkmark \\ I_{D2} = 12.5 \text{ mA} \end{cases}$

$g_{m2} = \sqrt{2\beta I_{D2}} = \sqrt{2 \times \frac{1}{4} \times \frac{1}{2}} = 0.5 \text{ mmho}$

$g_{m1} = \sqrt{2\beta I_{D1}} = \sqrt{2 \times \frac{1}{4} \times 1} = 0.7 \text{ mmho}$

$R_{out} = 3.3^k \parallel r_{ds} = 3.3^k$

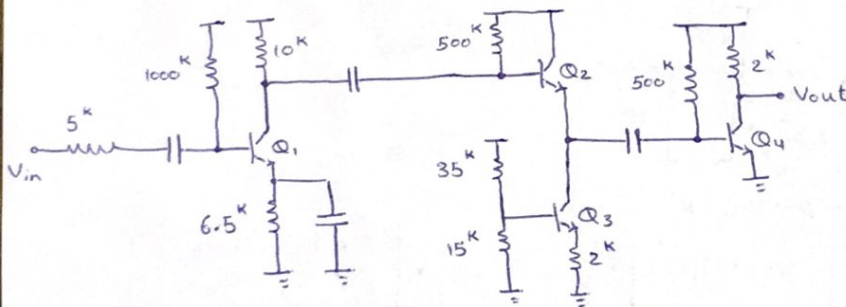
ac analysis:



$A_v = \frac{V_{out}}{V_{in}} = \frac{V_{out}}{V_A} \times \frac{V_A}{V_{in}} = [-g_{m2} (R_0 \parallel r_{ds})] \cdot [-g_{m1} (R_0 \parallel r_{ds})] = [-0.5 (3.3^k \parallel \infty)] \times [-0.7 (3^k \parallel \infty)]$
 $= 3.46$

7. Calculate the voltage gain of the structure depicted in the following figure.

The transistors are in the saturation region.



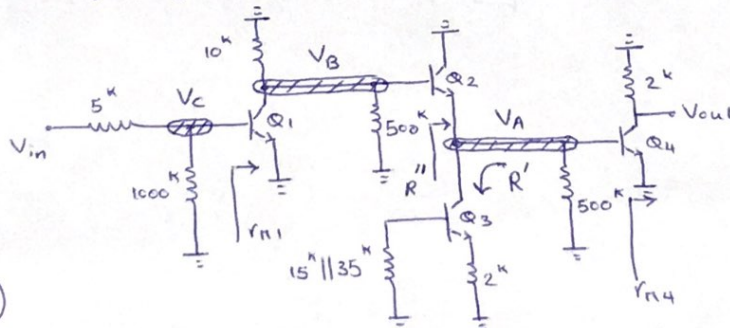
$V_A = 100^V$
 $V_T = 25 \text{ mV}$
 $\beta = 100$
 $I_{C1} = I_{C4} = 1 \text{ mA}$
 $I_{C2} = 0.5 \text{ mA}$

$= 100^k$

$I_{C1} = I_{C4} = 1 \text{ mA} \rightarrow g_{m1} = g_{m4} = 40 \text{ mmho} \rightarrow r_{n1} = r_{n4} = \frac{100}{40} = 2.5^k \rightarrow r_{o1} = r_{o4} = \frac{V_A}{I_C}$
 $I_{C2} = I_{C3} = 0.5 \text{ mA} \rightarrow g_{m2} = g_{m3} = 20 \text{ mmho} \rightarrow r_{n2} = r_{n3} = \frac{100}{20} = 5^k \rightarrow r_{o2} = r_{o3} = 200^k$

ac analysis:

hint: $R = R_B \parallel R_E \parallel \beta R_E$
 $R = r_o \left(1 + \frac{\beta R_E}{R_E + r_{n1} + R_B} \right)$

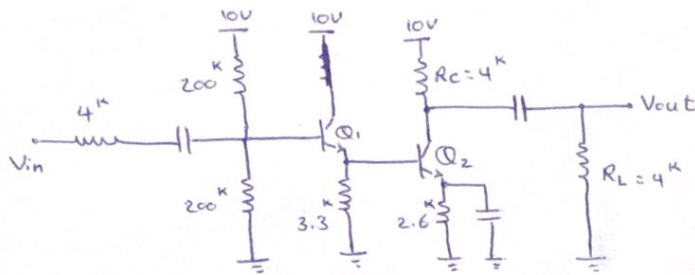


$R' = 200^k \left(1 + \frac{100 (2^k)}{2^k + 5^k + 15^k \parallel 35^k} \right)$

$R'' = r_{n2} + (\beta + 1) R_E$
 $= 5^k + 101 (R' \parallel 500^k \parallel 2.5^k)$

$A_v = \frac{V_{out}}{V_{in}} = \frac{V_{out}}{V_A} \times \frac{V_A}{V_B} \times \frac{V_B}{V_C} \times \frac{V_C}{V_{in}} = [-g_{m4} (R_{C4} \parallel r_{o4})] \times \left[\frac{R_{E2}}{R_{E2} + \frac{1}{g_{m2}}} \right] \times [-g_{m1} (R_{C1} \parallel r_{o1})]$
 $= \left[\frac{(r_{n1} \parallel 1000^k)}{(r_{n1} \parallel 1000^k) + 5^k} \right] = [-40 (2^k \parallel 100^k)] \times \left[\frac{500^k \parallel 2.5^k \parallel R'}{(500^k \parallel 2.5^k \parallel R') + \frac{1}{20}} \right] \times [-40 (10^k \parallel 500^k \parallel R'' \parallel 100^k)]$
 $\times \left[\frac{100^k \parallel 1000^k}{(100^k \parallel 1000^k) + 5^k} \right] \approx 9390$

8. Calculate the voltage gain in the following circuit:

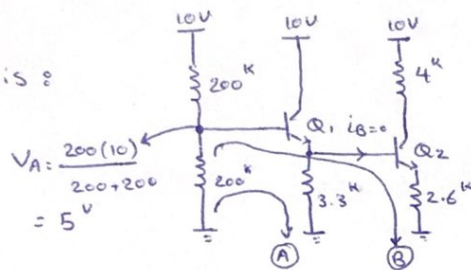


$$\beta_1 = \beta_2 = 100$$

$$V_{ce, sat} = 0.2$$

$$V_{be, on} = 0.7$$

dc analysis:



$$\text{KVL @ A: } -5V + (200k \parallel 200k) \frac{I_{C1}}{100} + 0.7 + 3.3k I_{C1} = 0$$

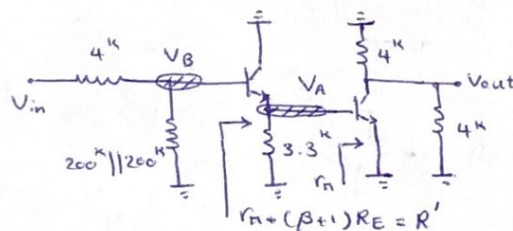
$$\Rightarrow I_{C1} = 1mA$$

$$\text{KVL @ B: } -5V + (200k \parallel 200k) \frac{I_{C1}}{100} + 0.7 + 0.7 + 2.6k I_{C2} = 0$$

$$\Rightarrow I_{C2} = 1mA$$

$$I_{C1} = I_{C2} = 1mA \rightarrow \begin{cases} g_{m1} = g_{m2} = 40 \text{ mho} \\ r_{\pi} = 2.5k \\ r_o = \infty \end{cases}$$

ac analysis:



$$A_v = \frac{V_{out}}{V_{in}} = \frac{V_{out}}{V_A} \times \frac{V_A}{V_B} \times \frac{V_B}{V_{in}} = \left[-g_m (R_C \parallel r_o) \right] \times \left[\frac{R_E}{R_E + \frac{1}{g_m}} \right] \times \left[\frac{R' \parallel 200k \parallel 200k}{R' \parallel 200k \parallel 200k + 4k} \right]$$

$$= \left[-40 (4k \parallel 4k \parallel \infty) \right] \times \left[\frac{3.3k \parallel 2.5k}{3.3k \parallel 2.5k + \frac{1}{40}} \right] \times \left[\frac{(2.5 + 101(3.3k)) \parallel 100k}{(2.5 + 101(3.3k)) \parallel 100k + 4k} \right] \approx -78.5$$